

Midium Power Transistors (50V / 1A)

2SCR513P

Structure

NPN Silicon epitaxial planar transistor

Features

- 1) Low saturation voltage, typically $V_{CE \, (sat)} = 0.35 V \, (Max.) \, (I_C \, / \, I_B = 500 mA \, / \, 25 mA)$
- 2) High speed switching

Applications

Driver

Packaging specifications

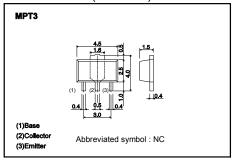
Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SCR513P		0

● Absolute maximum ratings (Ta = 25°C)

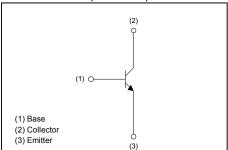
Parameter		Symbol	Limits	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I _C	1	Α
	Pulsed	I _{CP} *1	2	Α
Power dissipation		P _D *2	0.5	W
		P _D *3	2	W
Junction temperature		Tj	150	°C
Range of storage temperature		T _{stg}	-55 to 150	°C

^{*1} Pw=10ms, Single Pulse

• Dimensions (Unit : mm)



• Inner circuit (Unit : mm)



^{*2} Each terminal mounted on a recommended land.

^{*3} Mounted on a ceramic board. (40x40x0.7mm³)

2SCR513P Data Sheet

●Electrical characteristic (Ta = 25°C)

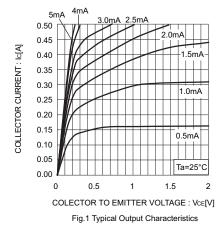
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV_CEO	50	-	-	V	I _C = 1mA	
Collector-base breakdown voltage	BV _{CBO}	50	-	-	V	I _C = 100μA	
Emitter-base breakdown voltage	BV_EBO	6	-	-	V	I _E = 100μA	
Collector cut-off current	I _{CBO}	-	-	1	μA	V _{CB} = 50V	
Emitter cut-off current	I _{EBO}	-	-	1	μA	V _{EB} = 4V	
Collector-emitter staturation voltage	V _{CE(sat)} *1	-	130	350	mV	I_C = 500mA, I_B = 25mA	
DC current gain	h_{FE}	180	-	450	-	V_{CE} = 2V, I_{C} = 50mA	
Transition frequency	f _T *1	-	360	-	MHz	V _{CE} = 10V I _E =-200mA, f=100MHz	
Collector output capacitance	C _{ob}	-	7	-	pF	V _{CB} = 10V, I _E =0A f=1MH z	
Turn-on time	t _{on} * ₂	-	40	_	ns	1 - 0 5 \ 1 - 50m \	
Storage time	t _{stg} * ₂	-	410	_	ns	I_{C} = 0.5A, I_{B1} = 50mA, I_{B2} =-50mA, V_{CC} ~10V	
Fall time	t _f *2	-	75	-	ns	1.82 33.11.1, V.C.C10V	

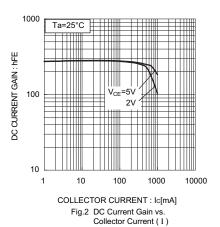
^{*1} Pulsed

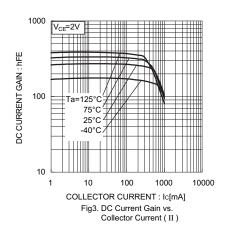
^{*2} See switching time test circuit

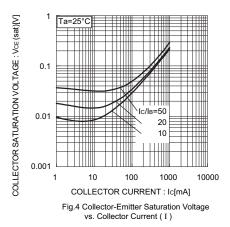
2SCR513P Data Sheet

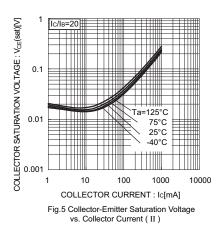
•Electrical characteristic curves

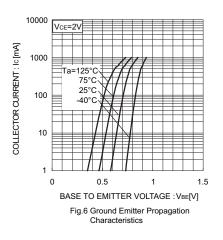


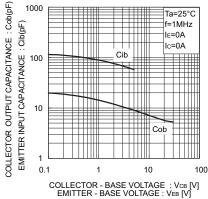


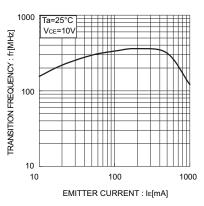












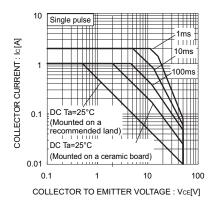


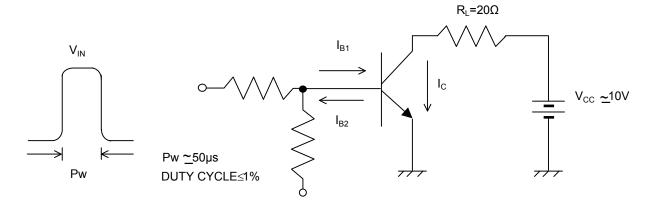
Fig.7 Emitter Input Capacitance vs. Emitter-Base Voltage Collector Output Capacitance vs. Collector-Base Voltage

Fig.8 Gain BandwidthProduct vs. Emitter Current

Fig.9 Safe Operating Area

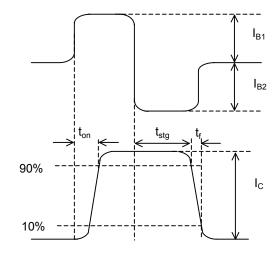
2SCR513P Data Sheet

•Switching time test circuit



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/